



Not for new design, this product will be obsoleted soon

BFR182T / BFR182TW

Vishay Semiconductors

Silicon NPN Planar RF Transistor

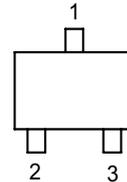
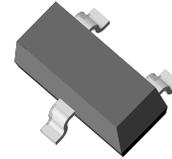
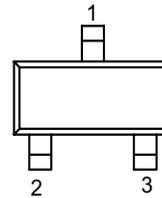
Features

- Low noise figure
- High power gain
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Applications

For low noise and high gain broadband amplifiers at collector currents from 1 mA to 20 mA.



Mechanical Data

Typ: BFR182T

Case: SOT-23 Plastic case

Weight: approx. 8.0 mg

Marking: RG

Pinning: 1 = Collector, 2 = Base, 3 = Emitter

Typ: BFR182TW

Case: SOT-323 Plastic case

Weight: approx. 6.0 mg

Marking: WRG

Pinning: 1 = Collector, 2 = Base, 3 = Emitter



Electrostatic sensitive device.
Observe precautions for handling.

13581

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Collector-base voltage		V _{CBO}	15	V
Collector-emitter voltage		V _{CEO}	10	V
Emitter-base voltage		V _{EBO}	2	V
Collector current		I _C	35	mA
Base current		I _B	5	mA
Total power dissipation	T _{amb} ≤ 60 °C	P _{tot}	200	mW
Junction temperature		T _j	150	°C
Storage temperature range		T _{stg}	- 65 to + 150	°C

Maximum Thermal Resistance

Parameter	Test condition	Symbol	Value	Unit
Junction ambient	1)	R _{thJA}	450	K/W

1) on glass fibre printed board (25 x 20 x 1.5) mm³ plated with 35 μm Cu

Electrical DC Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector-emitter cut-off current	V _{CE} = 15 V, V _{BE} = 0	I _{CES}			100	μA
Collector-base cut-off current	V _{CB} = 10 V, I _E = 0	I _{CBO}			100	nA
Emitter-base cut-off current	V _{EB} = 1 V, I _C = 0	I _{EBO}			1	μA
Collector-emitter breakdown voltage	I _C = 1 mA, I _B = 0	V _{(BR)CEO}	10			V
Collector-emitter saturation voltage	I _C = 30 mA, I _B = 3 mA	V _{CEsat}		0.1	0.4	V
DC forward current transfer ratio	V _{CE} = 6 V, I _C = 5 mA	h _{FE}	50	90		
	V _{CE} = 8 V, I _C = 20 mA	h _{FE}		100		

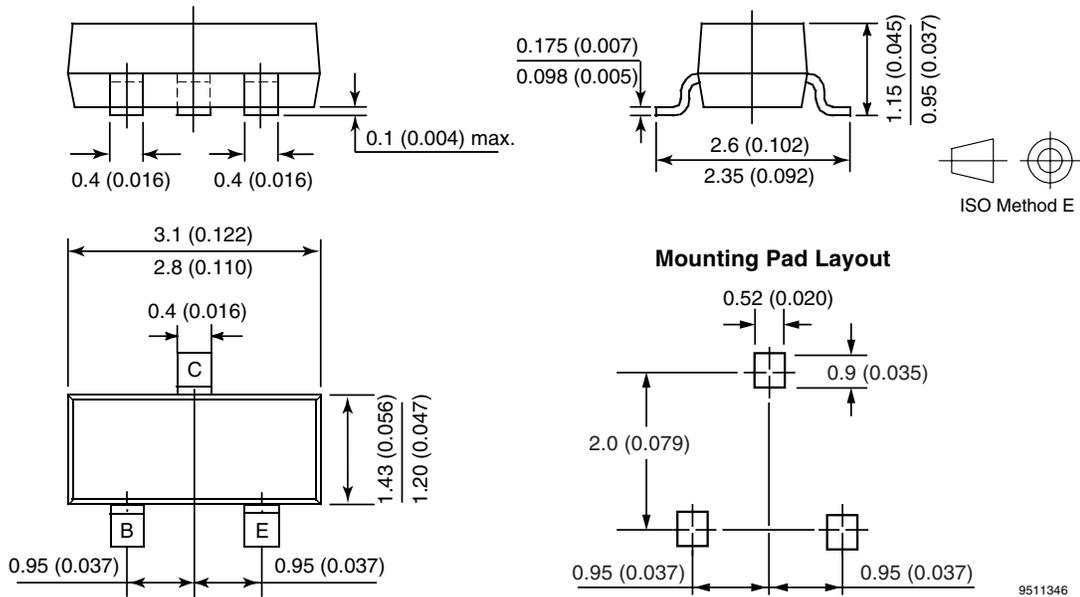


Electrical AC Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Transition frequency	V _{CE} = 6 V, I _C = 5 mA, f = 500 MHz	f _T		5.5		GHz
	V _{CE} = 8 V, I _C = 20 mA, f = 500 MHz	f _T		7.5		GHz
Collector-base capacitance	V _{CB} = 10 V, f = 1 MHz	C _{cb}		0.3		pF
Collector-emitter capacitance	V _{CE} = 10 V, f = 1 MHz	C _{ce}		0.2		pF
Emitter-base capacitance	V _{EB} = 0.5 V, f = 1 MHz	C _{eb}		0.65		pF
Noise figure	V _{CE} = 6 V, I _C = 5 mA, Z _S = Z _{Sopt} , f = 900 MHz	F		1.5		dB
	V _{CE} = 6 V, I _C = 5 mA, Z _S = Z _{Sopt} , f = 1.75 GHz	F		2.0		dB
Power gain	V _{CE} = 8 V, I _C = 20 mA, Z _S = 50 Ω, Z _L = Z _{Lopt} , f = 900 MHz	G _{pe}		15		dB
	V _{CE} = 8 V, I _C = 20 mA, Z _S = 50 Ω, Z _L = Z _{Lopt} , f = 1.75 GHz	G _{pe}		11		dB
Transducer gain	V _{CE} = 8 V, I _C = 20 mA, f = 900 MHz, Z ₀ = 50 Ω	S _{21e} ²		14		dB

Package Dimensions in mm (Inches)

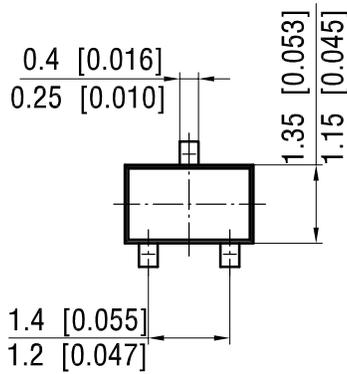
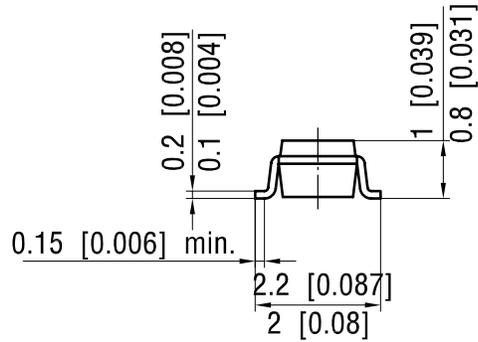
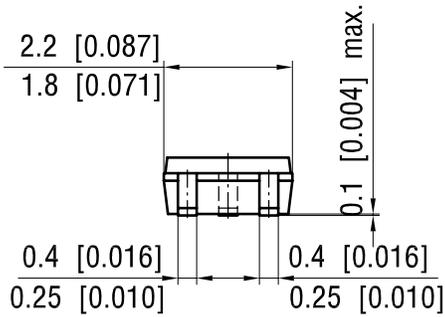


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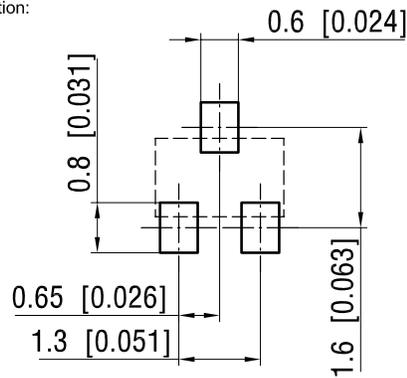


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Package Dimensions in mm (Inches)



foot print recommendation:



Rev. 4 - Date: 26.January.2005
Document no.:6.541-5040.01-4
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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

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